SDLS120 - MARCH 1974 - REVISED MARCH 1988

FUNCTION TABLE (each latch)

INP	JTS	OUTPUTS					
Đ	С	a	ā				
L	Н	L	н				
Н	Н	Н	L				
х	L	Ο0	$\overline{\alpha}_0$				

H= high level, L= low level, X= irrelevant $O_0=$ the level of Q before the high-to-low transition of G

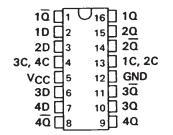
description

These latches are ideally suited for use as temporary storage for binary information between processing units and input/output or indicator units. Information present at a data (D) input is transferred to the Q output when the enable (C) is high and the Q output will follow the data input as long as the enable remains high. When the enable goes low, the information (that was present at the data input at the time the transition occurred) is retained at the Q output until the enable is permitted to go high.

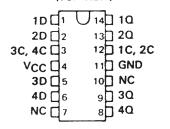
The '75 and 'LS75 feature complementary Q and \overline{Q} outputs from a 4-bit latch, and are available in various 16-pin packages. For higher component density applications, the '77 and 'LS77 4-bit latches are available in 14-pin flat packages.

These circuits are completely compatible with all popular TTL families. All inputs are diode-clamped to minimize transmission-line effects and simplify system design. Series 54 and 54LS devices are characterized for operation over the full military temperature range of –55°C to 125°C; Series 74, and 74LS devices are characterized for operation from 0°C to 70°C.

SN5475, SN54LS75 . . . J OR W PACKAGE SN7475 . . . N PACKAGE SN74LS75 . . . D OR N PACKAGE (TOP VIEW)

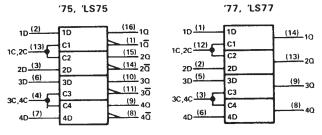


SN5477, SN54LS77 . . . W PACKAGE (TOP VIEW)



NC - No internal connection

logic symbols†



[†]These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

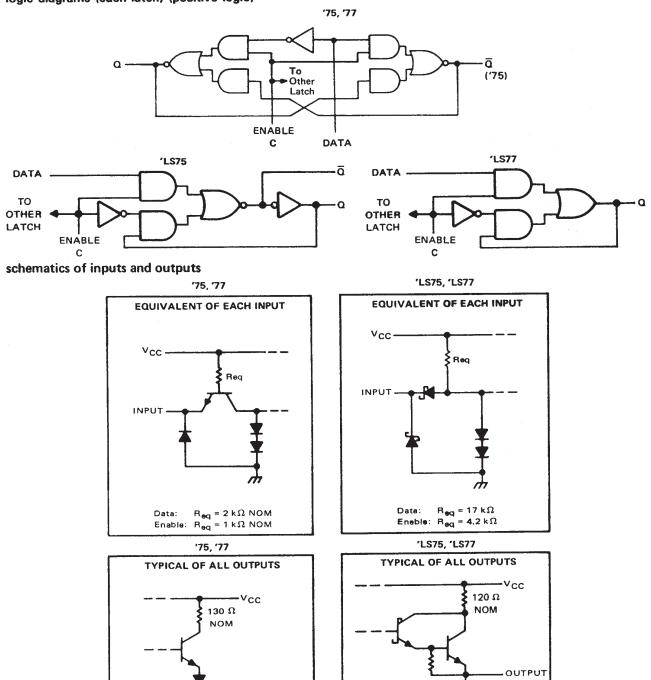
absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, VCC (See Note 1)		7 V
Interemitter voltage (see Note 2)		5.5 V
Operating free-air temperature range:	SN54'	– 55°C to 125°C
5	SN74'	0° C to 70°C
Storage temperature range		-65°C to 150°C

NOTES: 1. Voltage values are with respect to network ground terminal.

2. This is the voltage between two emitters of a multiple-emitter input transistor and is not applicable to the 'LS75 and 'LS77.

logic diagrams (each latch) (positive logic)





OUTPUT

recommended operating conditions

	SN5-	SN5475, SN5477			SN7475		
	MIN	NOM	MAX	MIN	NOM	MAX	UNIT
Supply voltage, V _{CC}	4.5	5	5.5	4.75	5	5.25	٧
High-level output current, IOH			-400			-400	μΑ
Low-level output current, IOL			16			16	mA
Width of enabling pulse, tw	20			20			ns
Setup time, t _{su}	20			20			ns
Hold time, th	5			5			ns
Operating free-air temperature, TA	55		125	0		70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER		TEST CO	MIN	TYP‡	MAX	UNIT	
VIH	High-level input voltage				2			V
VIL	Low-level input voltage						0.8	٧
VIK	Input clamp voltage		V _{CC} = MIN,	I _I = -12 mA			-1.5	٧
VoH	OH High-level output voltage		V _{CC} = M1N, V _{1L} = 0.8 V,	V _{1H} = 2 V, I _{OH} = -400 μA	2.4	3.4		٧
V _{OL}	L Low-level output voltage		V _{CC} = MIN, V _{IL} = 0.8 V,	V _{IH} = 2 V, I _{OL} = 16 mA		0.2	0.4	٧
11	Input current at maximum input voltage	out voltage		V ₁ = 5.5 V			1	mA
ЧН	High-level input current	D input	V _{CC} = MAX,	V _I = 2.4 V			80	μΑ
		Cinput			ļ		160 -3.2	
ItL	Low-level input current	D input C input	V _{CC} = MAX,	V ₁ = 0.4 V			-6.4	mA
	8			SN54'	-20		-57	
los	IOS Short-circuit output current §		V _{CC} = MAX	SN74'	-18		-57	mA
	Continue		V _{CC} = MAX,	SN54'		32	46	
Icc	Supply current		See Note 3	SN74'		32	53	mA

 $^{^\}dagger$ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

switching characteristics, V_{CC} = 5 V, T_A = 25°C

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN T	YP I	MAX	UNIT
^t PLH			16	16	30		
tPHL	D	Q			14	25	ns
ФLН¶	5	ō	C. = 15 nE		24	40	ns
tPHL¶	\overline{Q} $C_L = 15 pF$,			7	15	""	
tPLH .	_		RL = 400 Ω, See Figure 1		16	30	ns
[†] PHL	C Q See Figure 1			7	15	""3	
tPLH¶	С	ā			16	30	ns
tPHL¶				7	15	113	

 $t_{PLH} \equiv propagation delay time, low-to-high-level output$



[‡]All typical values are at V_{CC} = 5 V, T_{A} = 25°C. § Not more than one output should be shorted at a time.

NOTE 3: I_{CC} is tested with all inputs grounded and all outputs open.

 $t_{PHL} \equiv$ propagation delay time, high-to-low-level output

These parameters are not applicable for the SN5477.

SN5475, SN5477, SN54LS75, SN54LS77 SN7475, SN74LS75 **4-BIT BISTABLE LATCHES**

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recommended operating conditions

	1 -	N54LS7 N54LS7		SN74LS75			UNIT
	MIN	NOM	MAX	MIN	NOM	MAX	
Supply voltage, VCC	4.5	5	5.5	4.75	5	5.25	٧
High-level output current, IOH			-400			-400	μА
Low-level output current, IOL			4			8	mA
Width of enabling pulse, tw	20			20			ns
Setup time, t _{su}	20			20			ns
Hold time, th	5			5			ns
Operating free-air temperature, TA	-55		125	0		70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS [†]			SN54LS75 SN54LS77			SN74LS75			UNIT							
						TYP‡	MAX	MIN	TYP [‡]	MAX								
VIH	High-level input voltage				2			2			٧							
VIL	Low-level input voltage						0.7			0.8	V							
VIK	Input clamp voltage	VCC = MIN,	I _I = -18 mA				-1.5			-1.5	٧							
Voн	High-level output voltage	V _{CC} = MIN, V _{IH} = 2 V, V _{IL} = V _{IL} max, I _{OH} = -400 μA		2.5	3.5		2.7	3.5		٧								
		V _{CC} = MIN,	V _{1H} = 2 V,	IOL = 4 mA		0.25	0.4		0.25	0.4	V							
VOL	Low-level output voltage	VIL = VIL max		IOL = 8 mA					0.35	0.5								
	Input current at		D input	D input			0.1			0.1	mA							
4	maximum input voltage	V _{CC} = MAX,	VCC = MAX,	VCC = MAX,	VCC = MAX,	ACC = MAY	VCC - MAX,	VCC - MAX,	VCC - MAX,	V ₁ = 7 V	Cinput			0.4			0.4	
		1	071/	D input			20			20	μА							
ЧН	High-level input current	V _{CC} = MAX,	$V_1 = 2.7 V$	Cinput			80			80								
			D input	D input			-0.4			-0.4	mA							
l IIL	L Low-level input current VCC = MAX, VI =	V _I = 0.4 V	C input			-1.6			-1.6	1111								
los	Short-circuit output current §	V _{CC} = MAX			-20		-100	-20		-100	mA							
<u> </u>		- MAY	Con Note 2	'LS75		6.3	12		6.3	12	mA							
1cc	Supply current	V _{CC} = MAX,	See Note 2	'LS77		6.9	13											

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

switching characteristics, VCC = 5 V, TA = 25° C

	FROM	то			'LS75			'LS77		UNIT
PARAMETER¶	(INPUT)	(OUTPUT)	TEST CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	Olali
[†] PLH	_				15	27		11	19	ns
tPHL	D	Q			9	17		9	17	
tPLH	_	ā			12	20				ns
tPHL	D	a	C _L = 15 pF,		7	15				
[†] PLH			Ω $R_L = 2 k\Omega$, See Figure 1		15	27		10	18	ns
tPHL	С	Q			14	25		10	18	
tPLH		=			16	30				ns
^t PHL	С	a a			7	15				

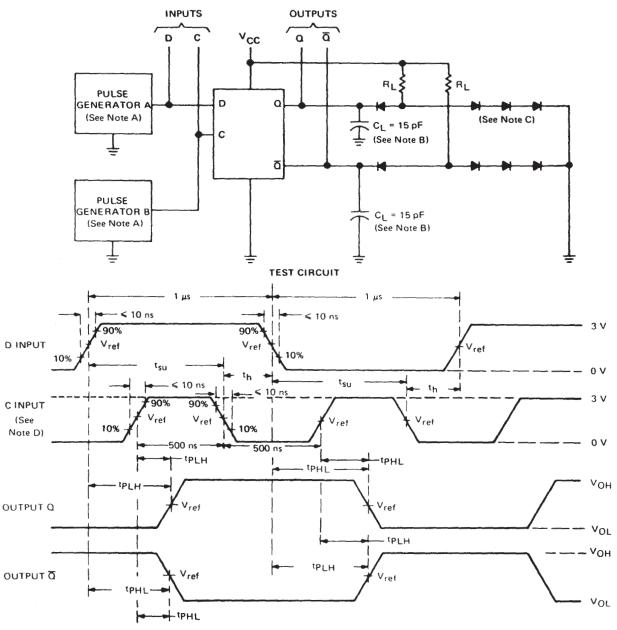
[¶] tpLH = propagation delay time, low-to-high-level output tpLH = propagation delay time, high-to-low-level output



[‡]All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25 ^{\circ}\text{C}$. Not more than one output should be shorted at a time, and duration of the short-circuit should not exceed one second NOTE 2: I_{CC} is tested with all inputs grounded and all outputs open.

PARAMETER MEASUREMENT INFORMATION

switching characteristics[†]



VOLTAGE WAVEFORMS

 $^{\dagger}\text{Complementary Q}$ outputs are on the '75 and 'LS75 only.

- NOTES: A. The pulse generators have the following characteristics: $Z_{out} \approx 50 \ \Omega$; for pulse generator A, PRR $\leq 500 \ kHz$; for pulse generator B, PRR $\leq 1 \ MHz$. Positions of D and C input pulses are varied with respect to each other to verify setup times.
 - B. C_L includes probe and jig capacitance.
 - C. All diodes are 1N3064 or equivalent.
 - D. When measuring propagation delay times from the D input, the corresponding C input must be held high.
 - E. For '75 and '77, $V_{ref} = 1.5 \text{ V}$; for 'LS75 and 'LS77, $V_{ref} = 1.3 \text{ V}$.

FIGURE 1



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